

## S34MS01G200BHB003

#### S34MS01G200BHB003 Information

Heisener.com	 S34MS01G200BHB003 Cypress Semiconductor Corp Integrated Circuits (ICs) Memory NAND - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



### S34MS01G200BHB003 Specifications

Manufacturer Part Number	S34MS01G200BHB003
Manufacturer	Cypress Semiconductor Corp
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	Automotive, AEC-Q100, MS-2
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	1Gb (128M x 8)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	45ns
Access Time	45ns
Voltage - Supply	1.7 V ~ 1.95 V
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

#### S34MS01G200BHB003 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE BUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### S34MS01G200BHB003 Payment Methods



If you have any question about S34MS01G200BHB003, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com